2.5V / 3.3V Differential 2 X 2 Crosspoint Switch with LVPECL Outputs

Multi-Level Inputs w/ Internal Termination

Description

The NB6L72 is a high–bandwidth fully differential 2 x 2 Crosspoint Switch with internal source termination and LVPECL output structure, optimized for low skew and minimal jitter. The differential inputs incorporate internal 50 Ω termination resistors and will accept LVPECL, CML, LVDS, LVCMOS, or LVTTL logic levels. The SELECT inputs are single–ended and can be driven with LVCMOS/LVTTL.

The differential LVPECL outputs provide 800 mV output swings when externally terminated with a 50 Ω resistor to V_{CC} – 2.0 V.

The device is offered in a small 3 mm x 3 mm 16–pin QFN package.

The NB6L72 is a member of the ECLinPS MAX^m family of high performance products.

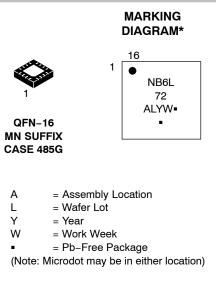
Features

- Maximum Input Clock Frequency > 3.0GHz
- Maximum Input Data Rate > 5 Gb/s
- 425 ps Typical Propagation Delay
- 100 ps Typical Rise and Fall Times
- 0.5 ps maximum RMS Clock Jitter
- LVPECL, CML or LVDS Input Compatible
- Differential LVPECL Outputs, 780 mV Amplitude, Typical
- Operating Range: $V_{CC} = 2.375$ V to 3.63 V with GND = 0 V
- Internal 50 Ω Input Termination Provided
- Functionally Compatible with Existing 2.5 V/3.3 V LVEL, LVEP, EP, and SG Devices
- -40°C to +85°C Ambient Operating Temperature
- These are Pb-Free Devices



ON Semiconductor®

http://onsemi.com



^{*}For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

1

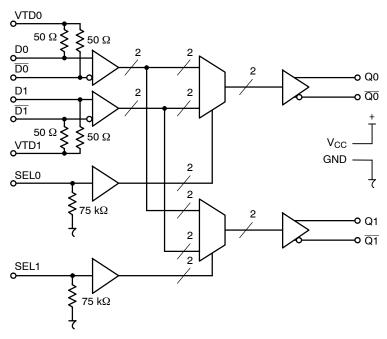


Figure 1. Logic/Block Diagram

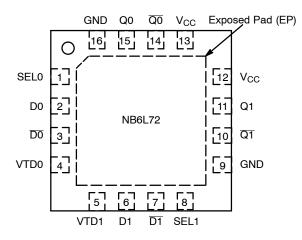


Figure 2. Pin Configuration (Top View)

Table 2 PIN DESCRIPTION

Table 1. INPUT/OUTPUT SELECT TRUTH TABLE

SEL0*	SEL1*	Q0	Q1
L	L	D0	D0
Н	L	D1	D0
L	Н	D0	D1
Н	Н	D1	D1

*Defaults LOW when left open

Pin	Name	I/O	Description
1	SEL0	LVTTL, LVCMOS Input	Select Logic Input control that selects D0 or D1 to output Q0. See Table 1, Select Input Function Table. Pin defaults LOW when left open
2	D0	LVPECL, CML, LVDS, LVTTL, LVCMOS, Input	Noninverted Differential Input. Note 1.
3	DO	LVPECL, CML, LVDS, LVTTL, LVCMOS, Input	Inverted Differential Input. Note 1.
4	VTD0	-	Internal 50 Ω Termination Pin. Note 1.
5	VTD1	-	Internal 50 Ω termination pin. Note 1.
6	D1	LVPECL, CML, LVDS, LVTTL, LVCMOS, Input	Noninverted Differential Input. Note 1.
7	D1	LVPECL, CML, LVDS, LVTTL, LVCMOS, Input	Inverted Differential Input. Note 1.
8	SEL1	LVTTL,LVCMOS Input	Select Logic Input control that selects D0 or D1 to output Q1. See Table 1, Select Input Function Table. Pin defaults LOW when left open
9	GND	-	Negative Supply Voltage
10	Q1	LVPECL Output	Inverted Differential Output. Typically Terminated with 50 Ω Resistor to V_{CC} – 2.0 V.
11	Q1	LVPECL Output	Noninverted Differential Output. Typically Terminated with 50 Ω Resistor to V _{CC} – 2.0 V.
12	V _{CC}	-	Positive Supply Voltage
13	V _{CC}	-	Positive Supply Voltage
14	Q0	LVPECL Output	Inverted Differential Reset Input. Typically Terminated with 50 Ω Resistor to V_{CC} – 2.0 V.
15	Q0	LVPECL Output	Noninverted Differential Reset Input. Typically Terminated with 50 Ω Resistor to V _{CC} – 2.0 V.
16	GND	-	Negative Supply Voltage
-	EP	-	The Exposed Pad (EP) on the QFN-16 package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be attached to a heat-sinking conduit. The pad is not electrically connected to the die, but is recommended to be electrically and thermally connected to GND on the PC board.

1. In the differential configuration when the input termination pin (VTDn, VTDn) are connected to a common termination voltage or left open, and if no signal is applied on Dn/Dn input, then the device will be susceptible to self-oscillation.
All V_{CC} and GND pins must be externally connected to a power supply for proper operation.

Table 3. ATTRIBUTES

Characteristics		Value
ESD Protection	Human Body Model Machine Model	> 2 kV > 200 V
Moisture Sensitivity	16–QFN	Level 1
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count		
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test		

For additional information, see Application Note AND8003/D.

Table 4. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	Positive Power Supply	GND = 0 V		4.0	V
V _{IO}	Positive Input/Output Voltage	GND = 0 V	$-0.5\leqV_{\text{IO}}\leqV_{\text{CC}}+0.5$	4.0	V
V _{INPP}	Differential Input Voltage $ D - \overline{D} $			2.8	V
I _{IN}	Input Current Through R_T (50 Ω Resistor)	Static Surge		45 80	mA mA
I _{OUT}	Output Current (LVPECL Output)	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range	QFN-16		-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient) (Note 3)	0 lfpm 500 lfpm	QFN-16 QFN-16	42 35	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	(Note 3)	QFN-16	4	°C/W
T _{sol}	Wave Solder Pb-Free			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

3. JEDEC standard multilayer board - 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

Symbol	Characteristic		Min	Тур	Max	Unit
POWER	SUPPLY CURRENT					
I _{CC}	Power Supply Current (Inputs and Outputs Open)		40	60	80	mA
LVPECL	OUTPUTS (Notes 4 and 5)					
V _{OH}	Output HIGH Voltage	V _{CC} = 3.3 V V _{CC} = 2.5 V	V _{CC} – 1075 2225 1425	V _{CC} – 950 2350 1550	V _{CC} - 825 2475 1675	mV
V _{OL}		V _{CC} = 3.3 V V _{CC} = 2.5 V	V _{CC} – 1825 1475 675	V _{CC} – 1725 1575 775	V _{CC} – 1625 1675 875	mV
DIFFERE	ENTIAL INPUT DRIVEN SINGLE-ENDED (see Figures 4	4 and 5) (Note	6)			
V _{th}	Input Threshold Reference Voltage Range (Note 7)		1125		V _{CC} – 75	mV
V _{IH}	Single-ended Input HIGH Voltage		V _{th} + 75		V _{CC}	mV
VIL	Single-ended Input LOW Voltage		GND		V _{th} – 75	mV
V _{ISE}	Single-ended Input Voltage Amplitude (V _{IH} - V _{IL})		150		2800	mV
DIFFERE	ENTIAL INPUTS DRIVEN DIFFERENTIALLY (see Figure	es 7 and 9)				
V _{IHD}	Differential Input HIGH Voltage		1200		V _{CC}	mV
V _{ILD}	Differential Input LOW Voltage		GND		V _{CC} – 150	mV
V _{ID}	Differential Input Voltage (Dn, Dn) (V _{IHD} - V _{ILD})		150		2800	mV
V _{CMR}	Input Common Mode Range (Differential Configuration) (Note 9)	1125		V _{CC} – 75	mV
I _{IH}	Input HIGH Current Dn/Dn, (VTDn/VTDn Open)		-10		50	μA
I _{IL}	Input LOW Current Dn/Dn, (VTDn/VTDn Open)		-50		10	μΑ
SINGLE-	ENDED LVCMOS/LVTTL CONTROL INPUTS					
VIH	Single-ended Input HIGH Voltage		2000		V _{CC}	mV
VIL	Single-ended Input LOW Voltage		GND		800	mV
I _{IH}	Input HIGH Current		-10		10	μA
IIL	Input LOW Current		-150		0	μA
TERMINA	ATION RESISTORS			-	-	-
R _{TIN}	Internal Input Termination Resistor		40	50	60	Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

4. LVPECL outputs loaded with 50 Ω to V_{CC} – 2.0 V for proper operation. 5. Input and output parameters vary 1:1 with V_{CC}.

V_{th}, V_{IH}, V_{IL}, and V_{ISE} parameters must be complied with simultaneously.
 V_{th} is applied to the complementary input when operating in single–ended mode.

8.

 V_{IHD} , V_{ILD} , V_{ID} and V_{CMR} parameters must be complied with simultaneously. V_{CMR} minimum varies 1:1 with GND, V_{CMR} max varies 1:1 with V_{CC} . The V_{CMR} range is referenced to the most positive side of the differential 9. input signal.

Table 6. AC CHARACTERISTICS $V_{CC} = 2.375$ V to 3.63 V, $V_{EE} = 0$ V, or $V_{CC} = 0$ V, $V_{EE} = -2.375$ V to -3.63 V,

 $T_A = -40^{\circ}C$ to +85°C; (Note 10)

Symbol	Characteristic		Min	Тур	Max	Unit
V _{OUTPP}	Output Voltage Amplitude (@ V _{INPPmin}) (Note 14) (See Figure 4)	$\begin{array}{l} f_{in} \leq 1.5 \text{ GHz} \\ f_{in} \leq 2.5 \text{ GHz} \\ f_{in} \leq 3.0 \text{ GHz} \end{array}$	520 380 320	800 650 500		mV
t _{PLH} , t _{PHL}	Propagation Delay (@0.5GHz)	Dn to Qn SELn to Qn	325	425	525	ps
t _{SKEW}	Duty Cycle Skew (Note 11) Within Device Skew Device to Device Skew (Note 12)			5	20 15 80	ps
t _{DC}	Output Clock Duty Cycle (Reference Duty Cycle = 50%)	f _{in} ≤3.0 GHz	40	50	60	%
t _{JITTER}	RMS Random Clock Jitter (Note 13)	f _{in} = 2.5 GHz f _{in} = 3.0 GHz		0.2 0.3	0.5 1	ps
V _{INPP}	Input Voltage Swing/Sensitivity (Differential Configuration) (Note 14)		150		2800	mV
t _r ,t _f	Output Rise/Fall Times @ 0.5 GHz (20% – 80%)	Q, <u>Q</u>		100	160	ps

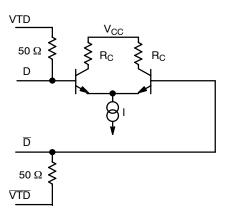
NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

10. Measured by forcing V_{INPP} (minimum) from a 50% duty cycle clock source. All loading with an external $R_L = 50 \Omega$ to $V_{CC} - 2.0 V$. Input edge rates 40 ps (20% - 80%).

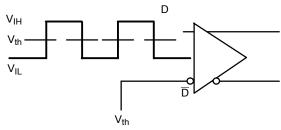
11. Duty cycle skew is measured between differential outputs using the deviations of the sum of T_{pw^-} and T_{pw^+} @ 0.5 GHz. 12. Device to device skew is measured between outputs under identical transition @ 0.5 GHz.

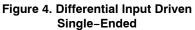
13. Additive RMS jitter with 50% duty cycle clock signal.

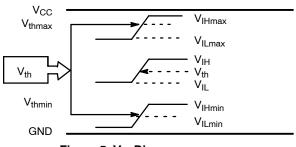
14. Input and output voltage swing is a single-ended measurement operating in differential mode.



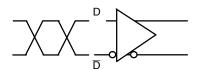




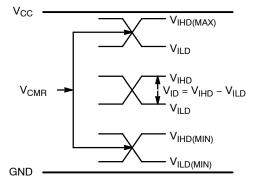




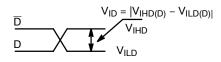




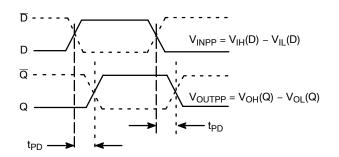














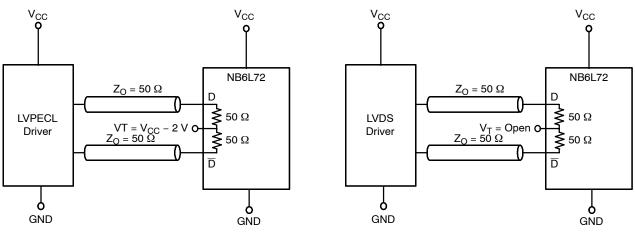
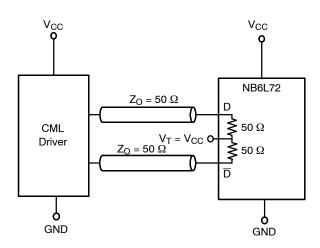
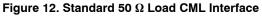
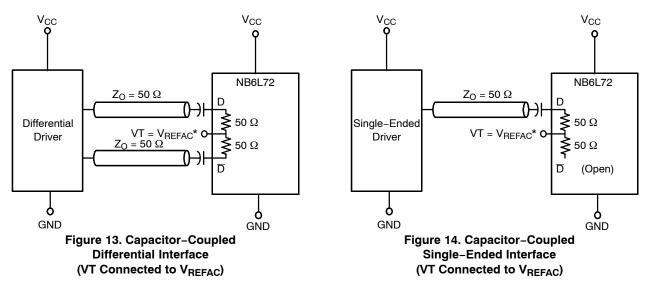




Figure 11. LVDS Interface







*V_{REFAC} bypassed to ground with a 0.01 μF capacitor

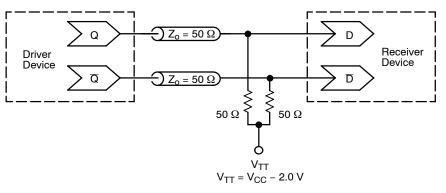


Figure 15. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

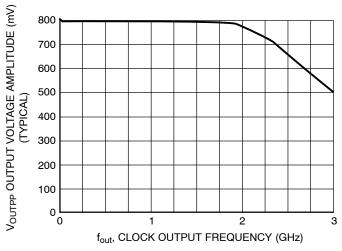


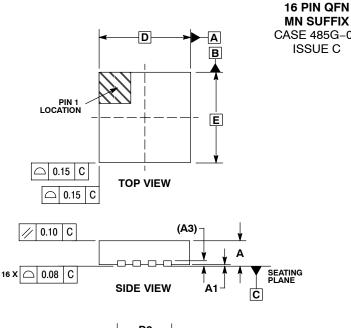
Figure 16. Output Voltage Amplitude (V_{OUTPP}) versus Output Frequency at Ambient Temperature (Typical)

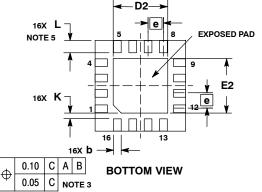
ORDERING INFORMATION

Device	Package	Shipping [†]
NB6L72MNG	QFN-16 (Pb-free)	123 Units / Rail
NB6L72MNR2G	QFN-16 (Pb-free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS





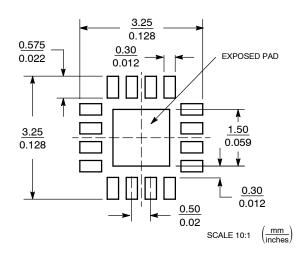
MN SUFFIX CASE 485G-01 ISSUE C

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED
- TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED
- PAD AS WELL AS THE TERMINALS. Lmax CONDITION CAN NOT VIOLATE 0.2 MM 5. MINIMUM SPACING BETWEEN LEAD TIP AND FLAG

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.80	1.00	
A1	0.00	0.05	
A3	0.20 REF		
b	0.18	0.30	
D	3.00	BSC	
D2	1.65	1.85	
Е	3.00	BSC	
E2	1.65	1.85	
е	0.50 BSC		
К	0.18	TYP	
L	0.30	0.50	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ECLinPS MAX is a trademark of Semiconductor Components Industries, LLC (SCILLC).

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.